UBA20270

600 V Driver IC for dimmable compact fluorescent lamps

Rev. 2 — 8 September 2011

Product data sheet

1. General description

The UBA20270 is a high-voltage power IC intended to control higher powered self ballasted Compact Fluorescent Lamp (CFL) lighting applications. The UBA20270 is a controller circuit with advanced features for dimming and has a lamp current controlled boost feature for boosting cold (amalgam) CFLs.

The controller contains a half-bridge drive function for CFL, a high-voltage level-shift circuit with integrated bootstrap diode. In addition, the controller contains an oscillator function, a current control function both for preheat and burn, a timer function and protection circuits. The UBA20270 is supplied via a dV/dt current charge supply circuit from the half-bridge circuit.

Remark: Mains voltages noted are AC.

2. Features and benefits

2.1 Half-bridge features

Integrated high-voltage level-shift function with integrated bootstrap diode

2.2 Preheat and ignition features

- Coil saturation protection during ignition
- Adjustable preheat time
- Adjustable preheat current
- Ignition lamp current detection

2.3 Lamp boost features

- Adjustable boost timing
- Fixed boost current ratio of 1.5
- Gradually boost to burn transition timing

2.4 Dim features

- Continuously variable dimming function for standard phase cut dimmers
- Natural dimming curve by logarithmic correction
- Adjustable Minimum Dimming Level (MDL)
- Controlled lamp ON/OFF



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2.5 Protection

- OverCurrent Protection (OCP) in boost and burn state
- Capacitive Mode Protection (CMP)
- OverPower Protection (OPP)
- Power-down function
- OverTemperature Protection (OTP)

2.6 Other features

- Current controlled operating in boost and burn state
- External power-down function
- Lamp flicker suppression

3. Applications

Dimmable compact fluorescent lamps for power levels above 20 W and for universal mains voltages.

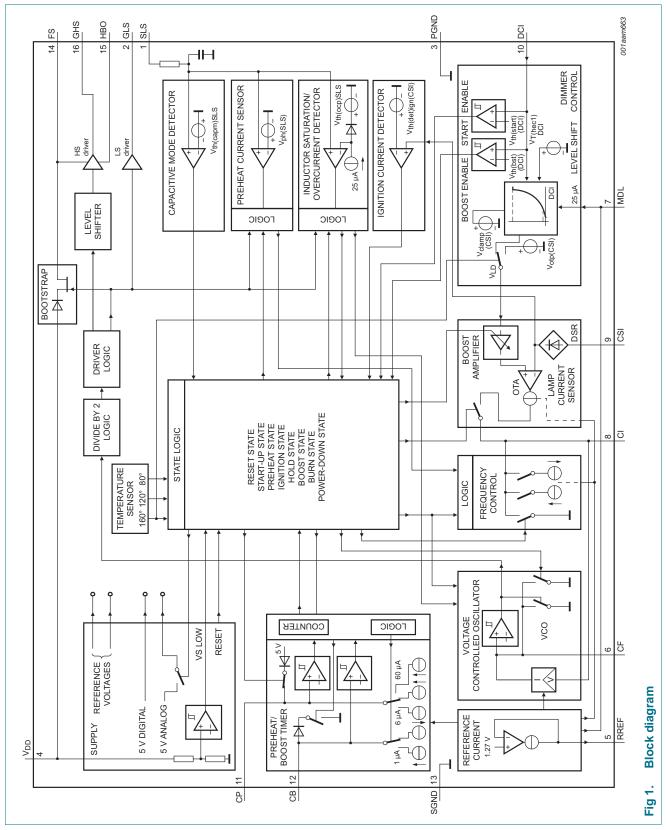
4. Ordering information

Table 1. Ordering information

Type number	Package					
	Name	Description	Version			
UBA20270T/N1	SO16	Plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			

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5. Block diagram



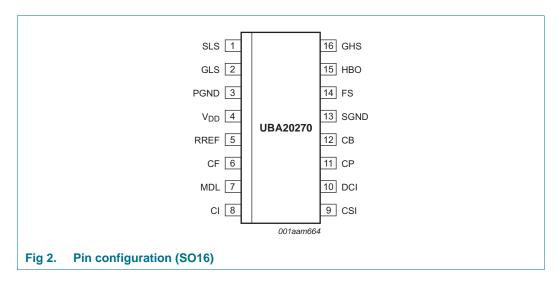
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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

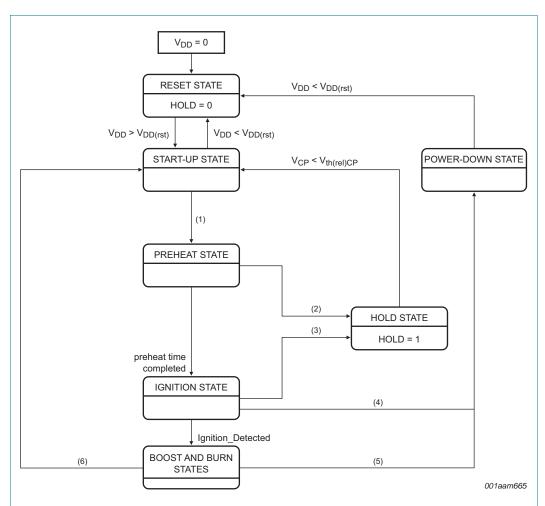
Symbol	Pin	Description
SLS	1	source low-side switch input
GLS	2	low-side gate driver output
PGND	3	power ground
V_{DD}	4	low voltage supply
RREF	5	internal reference current input
CF	6	voltage controlled oscillator capacitor
MDL	7	minimum dimming level input
CI	8	voltage controlled oscillator input integrating capacitor
CSI	9	current feedback sense input
DCI	10	dimming level input
CP	11	preheat timing capacitor
СВ	12	boost timing capacitor
SGND	13	signal ground
FS	14	floating supply voltage
НВО	15	half-bridge output
GHS	16	high-side gate driver output

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7. Functional description

The UBA20270 is an IC for driving external half-bridge MOSFETs in self ballasted high-power CFL and their derivatives. The UBA20270 is equipped with a dimming control input that has a logarithmic corrected natural dimming function. This function enables a less sensitive brightness control of the lamp at low dim levels.

The UBA20270 is rated up to a maximum continuous rectified mains voltage of 500 V (peak 600 V). The UBA20270 includes all the necessary functions for preheat, ignition, boost, and on-state operation of the lamp. In addition, the UBA20270 includes several protection measures that safeguard the functioning of the CFL and controller. The controller states are shown in Figure 3.



- (1) $V_{DD} > V_{DD(start)}$ AND $V_{i(DCI)} > V_{th(start)DCI}$ AND (HOLD = 0 OR $V_{CP} < V_{th(rel)CP}$)
- (2) V_{DD} < V_{DD(stop)} OR V_{i(DCI)} < V_{th(start)DCI} V_{th(hvs)DCI}
- (3) (End of ignition time AND HOLD = 0) OR $V_{DD} < V_{DD(stop)}$ OR $V_{i(DCI)} < V_{th(start)DCI} V_{th(hys)DCI}$
- (4) End of ignition time AND HOLD = 1
- (5) $V_{CP} < V_{th(pd)CP}$ OR overcurrent fault time > $\frac{1}{10}$ t_{ph} OR $f_{bridge(max)}$ detected in capacitive mode
- (6) $V_{DD} < V_{DD(stop)} OR V_{i(DCI)} < V_{th(start)DCI} V_{th(hys)DCI}$

Fig 3. State diagram

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7.1 Lamp start-up cycle

7.1.1 Reset state

The UBA20270 is in a reset state while the supply voltage on the V_{DD} pin is below the $V_{DD(rst)}$ level. In the reset state, a part of the internal supply is turned off, all registers, counters and timers are undefined. In addition, the hold state latch is reset and both the applied external high and low-side transistor (Q1, Q2) are non-conductive. During power-up, the low voltage supply capacitor on the V_{DD} pin is charged via an external start-up resistor. When the voltage on the V_{DD} pin is above the $V_{DD(rst)}$ level, the start-up state is entered. The UBA20270 enters the reset state when the supply voltage on the V_{DD} pin drops lower than $V_{DD(rst)}$.

7.1.2 Start-up state

Start-up is achieved by charging the low voltage supply capacitor on the V_{DD} pin via an external start-up resistor. At start-up the High-Side (HS) transistor is non-conductive and the Low-Side (LS) is conductive to enable charging of the bootstrap capacitor. This capacitor supplies the HS driver and level shifter circuit connected between the FS and HBO pin. A DC reset circuit is incorporated in the ICs HS driver. This circuit ensures that lower than the lockout voltage on the FS pin the output voltage (V_{GHS} - V_{HBO}) is zero.

As the start-up state is entered, the circuit only starts oscillating when the low voltage supply (V_{DD}) reaches the value of $V_{DD(start)}$ AND $V_{i(DCI)} > V_{th(start)DCI}$. The circuit starts oscillating at $f_{bridge(max)}$.

The circuit enters the preheat state as soon as the capacitor on the CP pin is charged to a voltage level above $V_{th(CP)max}$. To remain oscillating, the V_{DD} voltage must remain higher than $V_{DD(stop)}$ and lower than the upper limit $V_{DD(clamp)}$. In addition, the typical voltage level on the DCI pin must be higher than $V_{th(start)DCI} - V_{th(hys)DCI} = 0.24 \text{ V}$.

An UnderVoltage LockOut (UVLO) is implemented on the DCI pin to create a guaranteed turn-off for multiple lamps when the lamps are at low dim levels. The UVLO also guarantees that there is a preheat phase when the dim level is turned up again.

The typical turn-on level on the DCI pin is set to lower than $V_{th(start)DCI} = 0.36 \text{ V}$, else it increases the turn-on hysteresis of the lamp. This level enables the UBA20270 to perform a stable ignition of the lamp when there is already sufficient power from the dimmer at lower dim levels.

During the start-up state, the voltage on the CF pin is at zero and the CB pin is close to zero. The voltage on the CP pin rises to higher than $V_{th(CP)max}$ level during the start-up state. See Figure 9.

7.1.3 Preheat state

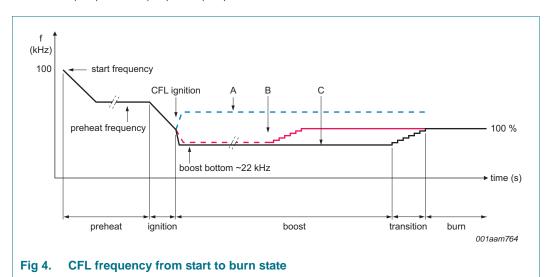
Starting at $f_{bridge(max)}$, the frequency decreases by charging capacitor C_{Cl} via an output current circuit controlled by the preheat current sensor circuit. This state continues until the momentary value of the voltage across sense resistor R_{SLS} reaches the internally fixed preheat voltage level (SLS pin). At this level, the current of the preheat current sensor reaches a charge and discharge balanced state on capacitor C_{Cl} to set the frequency.

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The preheat time consists of eight saw-toothed pulses at the CP pin. Preheat begins as soon as the capacitor on the CP pin is charged to a voltage higher than $V_{th(CP)max}$. During the preheat time, the current feedback sensor circuit (input CSI pin) is disabled. To increase noise immunity, an internal filter of 30 ns is included at the SLS pin.

If during preheat, the level on the DCI pin drops lower than $V_{th(start)DCI} - V_{th(hys)DCI} = 0.24 \text{ V}$ or the V_{DD} pin drops lower than $V_{DD(stop)}$, the preheat state is immediately stopped. The circuit enters the hold state delaying a new preheat cycle. A fixed voltage drop on the preheat capacitor C_{CP} and a fixed discharge current on the CP pin sets the delay time.

A new preheat cycle starts after the CP pin level slowly discharges. This condition continues until $V_{CP} < V_{th(rel)CP}$ and recharges higher than $V_{th(CP)max}$ provided $V_{DD} > V_{DD(start)}$ AND $V_{i(DCI)} > V_{th(start)DCI}$. See <u>Figure 5</u>.

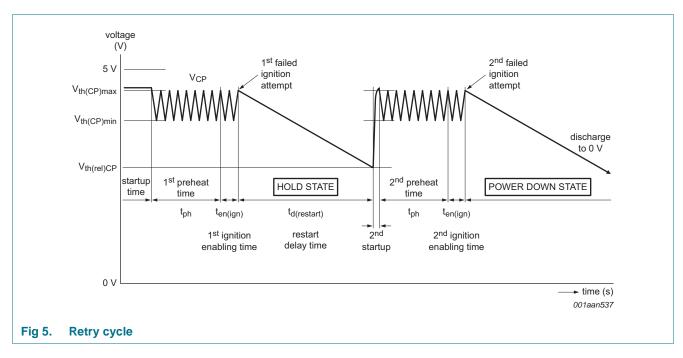


7.1.4 Ignition state

Directly after the preheat state has been completed, the ignition state is entered. In the ignition state, the frequency sweeps down due to charging of the capacitor C_{Cl} on the CI pin with an internally fixed current. See <u>Figure 4</u>. During this continuous decrease in frequency, the circuit approaches the resonant frequency of the resonant tank L2, C5. This results in a high voltage across the lamp to ignite the lamp. The current sensor circuit which monitors the voltage over resistor R_{CSI} detects lamp ignition. See <u>Figure 11</u>.

If the voltage on the CSI pin is above the typical ignition detection threshold voltage level of 0.6 V, lamp ignition is detected. The system then changes from ignition state to the boost or burn state. If no ignition is detected, the frequency decreases further to the minimum half-bridge frequency $f_{bridge(min)}$. To prevent continuous ignition attempts and over-heating of the application due to lamp damage, the UBA20270 only attempts to ignite the lamp twice after power-up. The ignition attempt counter is incremented when the lamp ignition threshold voltage on the CSI pin is not exceeded at the end of the ignition enabling time. If a second ignition attempt also exceeds the ignition time-out period, the IC enters the power-down state. See Figure 5.

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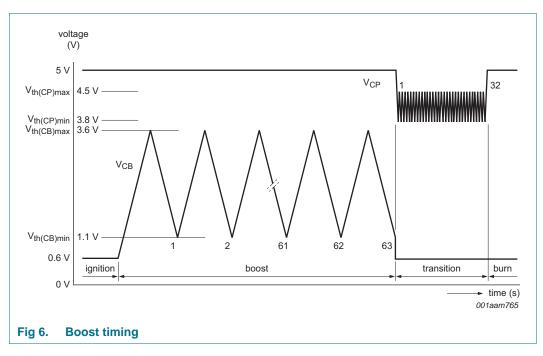
7.1.5 Boost state and transition to burn state

When ignition is detected by measuring lamp current on the CSI pin, the circuit enters the boost state. Figure 7 shows the boost and burn state in more detail. In the boost state, the nominal burn state lamp current can be increased with a fixed boost ratio of 1.5:1. This boosts up the slow luminescence increase of a cold amalgam CFL lamp, provided $V_{DCI} > V_{th(bst)DCI}$. If the IC is at a temperature $(T_{j(bp)bst})$ before entering the boost state, the burn state is bypassed.

A boost timing circuit is included to determine the boost time and transition to burn time. The circuit consists of a clock generator comprising C_{CB} , $R_{\text{ext}(RREF)}$ and a 64-step counter. When the timer is not operating, C_{CB} is discharged to lower than the $V_{\text{th}(CB)\text{min}}$ level of 1.1 V. This voltage, about 0.6 V, is still higher than the level at which the comparator on C_{CB} detects if the CB pin is shorted to ground.

The boost time consists of 63 saw-toothed pulses at the CB pin and automatically followed by the transition time at the CP pin. The 32 saw-tooth pulses form the transition time from boost to burn enabling a smooth transition between the current controlled boost and burn state. The total transition time is approximately four times the preheat time as shown in Figure 6.

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In the boost state, the lamp current feedback control circuit operates the same as in the burn state. This action is used to improve lamp stability. Lamp current boosted by a fixed ratio of 1.5 compared to the burn state, boosts up the slow luminescence increase of a cold CFL lamp. In the boost to burn transition time there is a slow 15-step ratio decrease from 1.5 to 1. For the transition to burn time, the preheat timer is reused and the boost ratio is gradually decreased in 15 steps from 1.5 to 1. The steps occur within 32 saw-toothed pulses on the CP pin. The 32 saw-toothed pulses form the transition time from boost to burn to enable a smooth transition between the current controlled boost and burn state. Given the application values of C_{CB} and $R_{ext(RREF)}$ a boost time of more than 300 s is possible. In addition to boost bypass at temperature $T_{j(bp)bst}$ (\approx 80 °C), there is a temperature protection function during the boost state of $T_{j(end)bst}$ (\approx 120 °C). If the IC temperature passes this level during boost, the transition timer is immediately started in order to enter the burn state faster. This action effectively reduces the boost time. See Figure 4 [B].

The current boost in the boost state does not start when $V_{i(DCI)}$ is lower than $V_{th(bst)DCI}$. Current boost ends when $V_{i(DCI)}$ is lower than $V_{th(bst)DCI} - V_{th(bst)hys(DCI)}$ without a boost transition. See Figure 4 [A].

Remark: If the CB pin is shorted to ground, the boost function is disabled. During such conditions, the bottom frequency $f_{bridge(min)}$ is 1.8 times higher than the boost bottom frequency $f_{bridge(bst)min}$.

7.1.6 Burn state

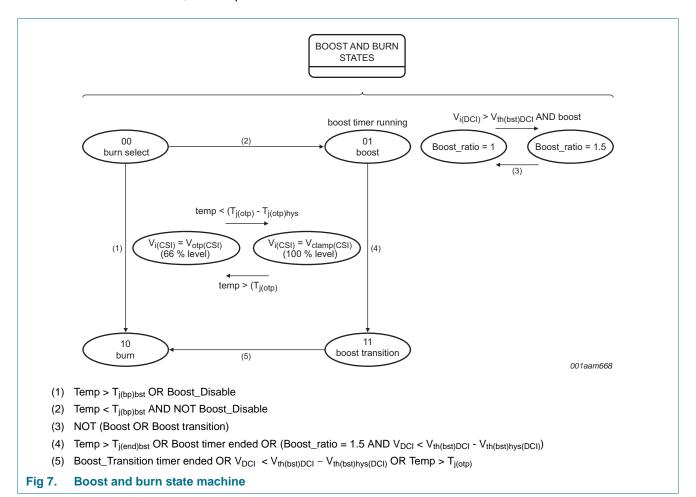
After the boost state, or when the boost state is bypassed burn state starts. The lamp current sensor circuit is still enabled. See $\underline{\text{Figure 4}}$ [A]. The CSI pin (current sense input) measures the RMS voltage across sense resistor R_{CSI} . It then passes through a Double-Sided Rectifier (DSR) circuit and fed towards an Operational Transconductor Amplifier (OTA). When the RMS voltage on the CSI pin reaches the internal reference level, the lamp current sensor circuit takes over the control of the lamp current. The

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internal current output of the OTA is transferred via an integrator on the CI pin to the input of the Voltage Controlled Oscillator (VCO). The VCO regulates the frequency and as a result, the lamp current.



7.1.7 Hold state

The hold state is a special state to reduce lamp flicker at deep dim levels, on or near dim and ignition threshold level. See Figure 3.

The hold state is entered following:

- a failed ignition attempt
- or when the low supply voltage V_{DD} is lower than V_{DD(stop)} in the ignition or preheat state
- or when V_{DCI} < V_{th(start)DCI} V_{th(hys)DCI} in the ignition or preheat state

A repeated aborted preheat or ignition cycle due to a drop in DCI voltage that is lower than $V_{th(start)DCI} - V_{th(hys)DCI}$ or a drop in supply voltage that is lower than $V_{DD(stop)}$ in preheat or ignition state does not increment the ignition attempt counter. The UBA20271/2 enters the hold state only delaying a new preheat cycle by the same time delay and mechanism. As shown in Figure 5 hold state retention time.

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When CP is lower than $V_{th(rel)CP}$, the IC is released from the hold state and moves to the start-up state. See <u>Figure 3</u>. Alternatively, the hold state ends when the supply voltage is lower than $V_{DD(rst)}$ and the IC is reset.

With a 470 nF capacitor on the CP pin, the typical hold state retention delay is between 1.0 seconds and 1.7 seconds. However, it depends on where the preheat cycle is cut off on the rising or falling edge of the preheat timing. The retention time for a failed ignition always starts from the top of the rising edge on the CP pin. See Figure 5. In the hold state, a latch is set (hold state latch = 1), the oscillator is stopped, transistor HS is non-conductive and transistor LS conducting. The voltage on pin V_{DD} alternates between $V_{DD(start)}$ and $V_{DD(stop)}$ as long as the voltage on the CP pin has not reached $V_{th(rel)CP}$. See Figure 5.

The alternating supply voltage is a result of the current drawn by the IC supply pin V_{DD} . The supply current is less than 220 μ A, when the supply voltage V_{DD} is increasing between $V_{DD(stop)}$ and $V_{DD(start)}$. The supply current is typically 2 mA when V_{DD} is decreasing between $V_{DD(start)}$ and $V_{DD(stop)}$. More current is drawn during the decreasing slope of V_{DD} as the internal analog supply is turned on when $V_{DD} > V_{DD(start)}$. This condition enables comparators in the IC to monitor the voltage on the CP pin and whether the supply voltage V_{DD} decreases lower than $V_{DD(stop)}$.

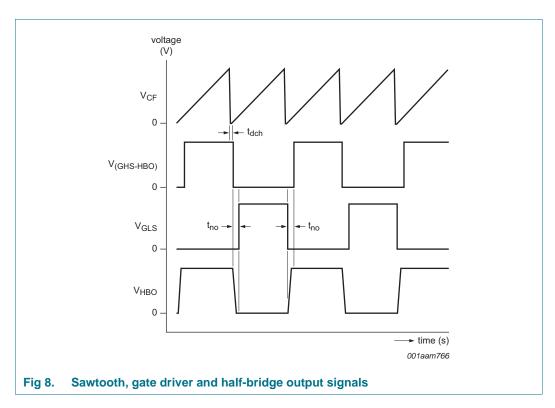
7.2 Oscillation and timing

7.2.1 Oscillation

The internal oscillator is a VCO circuit which generates a sawtooth waveform between the $V_{th(CF)max}$ level and 0 V. Capacitor C_{CF} , resistor $R_{ext(RREF)}$, and the voltage at the CI pin determine the frequency of the sawtooth. $R_{ext(RREF)}$ and C_{CF} determine the minimum and maximum switching frequencies. Their ratio is internally fixed. There are two ratios, the ratio between $f_{bridge(max)}$ and $f_{bridge(min)}$ is 2.5 and the ratio between $f_{bridge(max)}$ and $f_{bridge(bst)min}$ is 4.6. The sawtooth frequency is twice the half-bridge frequency.

Transistors HS (Q1) and LS (Q2) are brought into conduction with a duty cycle of approximately 50 %. Figure 8 provides an overview of the oscillator signal and driver signals. The oscillator starts oscillating at $f_{bridge(max)}$. The non-overlap time between the gate drive signals V_{GLS} and V_{GHS} is t_{no} .

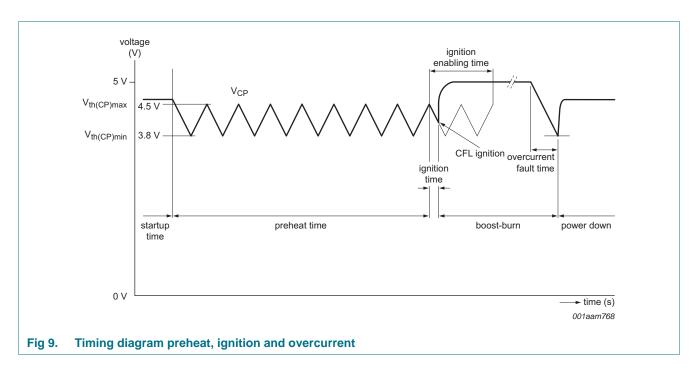
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7.2.2 Combined timing circuit

A combined timing circuit is included to determine the preheat time, ignition enabling time and overcurrent time, see <u>Figure 9</u>. The circuit consists of a clock generator defined by C_{CP} and $R_{ext(RREF)}$ and a counter. When the timer is not operating, C_{CP} is charged to 5 V. The timing circuit starts operating after the start-up state, as soon as the low supply voltage has reached $V_{DD(start)}$. Additionally the DCI input voltage must be higher than $V_{th(start)DCI}$ and the voltage on the CP pin must pass $V_{th(CP)max}$. The preheat time consists of eight saw-tooth pulses on the CP pin as shown in <u>Figure 9</u>. The maximum ignition enabling time following the preheat phase is two complete sawtooth (triangular) pulses. During the boost and burn state, part of the timer is used to generate the maximum overcurrent time (more than one half of the saw-toothed pulse). If a continuous overcurrent is detected, the timer starts.

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7.3 Natural linear dimming

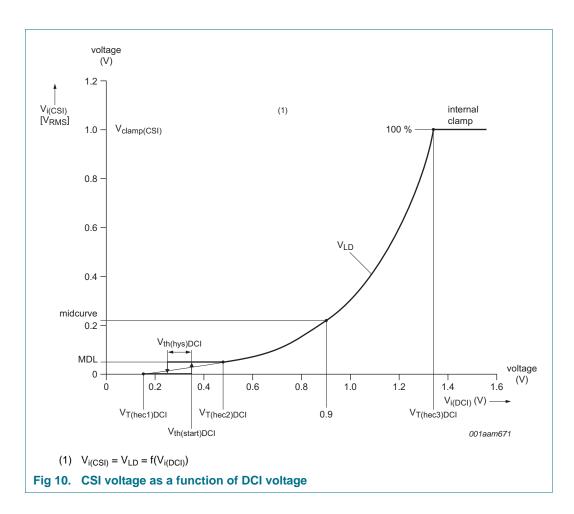
What determines the actual internal set point level used for the current control feedback loop is an external level applied via the DCI pin for dimming. The DCI voltage is a function of the phase cut angle of the applied dimmer. To ensure that the external input for the control on the DCI pin internally stays within a certain range, this input signal passes an internal linear to logarithmic conversion circuit followed by a limiting circuit.

The linear to logarithmic conversion circuit is designed to improve dimming control by correcting for the higher sensitivity of the human eye to small changes in low light levels. See <u>Figure 10</u>. The conversion circuit also provides a natural perceived linear brightness adjustment of the lamp.

The limiting circuit prevents the signal falling below the MDL or rising above the 100 % reference level of $V_{clamp(CSI)}$. The output of the linear to logarithmic conversion circuit is the actual reference voltage for the lamp current control loop. See signal V_{LD} in <u>Figure 1</u> (dimmer control block). When the IC is in the burn state, the voltage is equal to the RMS voltage on the CSI pin. When the control loop is regulating correctly, the upper limit is clamped at the 100 % reference level. This condition prevents lamp current values that are too high in mains overvoltage situations. See <u>Figure 10</u>.

The MDL level presets a minimum to which the lamp current clips at low dim levels and is adjustable via the MDL pin. An accurate minimum dimming voltage level is set by using an internal reference current (derived from the internal band gap reference circuit and resistor $R_{\text{ext}(RREF)}$) and an applied external resistor R_{MDL} on the MDL pin.

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7.4 Protection and power-down

7.4.1 Coil saturation protection

Coil saturation protection is integrated into the IC to allow for the use of small CFL lamps and use of small coils. Saturation of these coils is detected and excessive overcurrent due to saturation is prevented. Coil saturation protection is only enabled during the ignition state. To limit voltages and currents in the resonant circuit when there is no ignition or delayed ignition, a cycle-by-cycle control mechanism is used to prevent coil saturation. This control also limits the high peak current and dissipation in the half-bridge power transistors.

Coil saturation is detected by monitoring the voltage across the R_{SLS} resistor. A trigger is generated when this voltage exceeds the $V_{th(sat)SLS}$ level. When saturation is detected, a fixed current $\Delta I_{o(sat)CF}$ is injected into the C_{CF} capacitor to shorten the switching cycle of the half-bridge. The injected current is maintained until the end of the switching cycle. This action immediately increases the half-bridge switching frequency. Furthermore, in each successive cycle that coil saturation is detected, capacitor C_{CI} is discharged to enable an ignition time-out detection in the ignition state.

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Coil saturation protection is triggered when the voltage on the SLS pin exceeds $V_{th(sat)SLS}$. The voltage V_{SLS} on the SLS pin is also used to set the preheat current. The value of external resistor R_{SLS} determines this voltage.

7.4.2 OverCurrent Protection (OCP)

OCP is active in the burn and boost states (not during boost transition). When the peak absolute value of the voltage across the current sense resistor on the SLS pin exceeds the OCP reference level $V_{th(ocp)SLS}$, overcurrent is detected. A current $I_{o(CP)}$ is then sunk from the capacitor connected to the CP pin for the next full cycle. If the overcurrent is absent at the end of this cycle, the current is disabled. Instead a current, also equal to $I_{o(CP)}$, is sourced to the CP pin. If the overcurrent occurs in more than half the number of cycles, there is a net discharging of the capacitor connected to the CP pin. When the voltage, on the CP pin is lower than $V_{th(CP)min}$ the IC enters power-down mode. In a continuous overcurrent condition, the overcurrent time-out of $t_{fault(oc)}$ takes about $1/\!\!/_{10}\,t_{ph}$. The IC then enters the power-down mode. The $V_{th(ocp)SLS}$ level corresponds with the $V_{th(sat)SLS}$ level during the ignition state.

7.4.3 OverPower Protection (OPP)

OPP is active in boost and burn state. The lamp current is limited and regulated to its nominal designed lamp current in case overvoltage situations on the mains supply occur. The overpower comes into action when the DCI voltage, that regulates the lamp current is exceeding the maximum DCI input range. Internally the DCI voltage is clamped to the maximum input voltage level $V_{T(hec3)DCI}$, see <u>Figure 10</u>. The DCI clamp level is independent of any supply voltage fluctuations.

7.4.4 Capacitive Mode Protection (CMP)

CMP is active in the ignition, burn and boost states and during boost transition. The signal across resistor R_{SLS} also provides information about the switching behavior of the half-bridge. When conditions are normal, the current flows from the source of the LS transistor to the half-bridge when the LS transistor is switched on. This results in a negative voltage on the SLS pin. As the circuit yields to capacitive mode, the voltage decreases and eventually reverses polarity. The protection prevents this condition from happening by checking if the voltage on the SLS pin is higher than $V_{th(capm)SLS}$.

If the voltage across resistor R_{SLS} is above the $V_{th(capm)SLS}$ threshold when the LS transistor is switched on, the circuit assumes that it is in capacitive mode. When capacitive mode is detected, the currents from the OTA are disabled and the capacitive mode sink current, $I_{o(sink)CI}$, is enabled. This sink current discharges the capacitor/resistor circuitry on the CI pin and as a result gradually increase the half-bridge frequency. Discharge continues for the remainder of the current switching cycle, so the total current on CI is equal to the sink current. If capacitive mode persists, the action is repeated until capacitive mode is not detected. If the capacitive mode is no longer detected, the OTA starts regulating again.

If the conditions causing the capacitive mode persist, the OTA regulates the system back towards capacitive mode with the protection system taking control. The system operates on the edge of capacitive mode. During boost and burn state, if the load on the half-bridge continues to be capacitive at higher frequencies, CMP eventually drives the half-bridge to the maximum frequency $f_{bridge(max)}$. From this point, the IC enters power-down mode.

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7.4.5 Power-down mode

Power-down mode is entered when:

- a continuous overcurrent exceeds the maximum overcurrent time-out t_{fault(oc)}. Or over a longer period if the overcurrent occurs in more than half the number of cycles as soon as V_{th(CP)min} is reached.
- during the boost or the burn state f_{bridge(max)} is reached due to capacitive mode detection
- two consecutive failed lamp ignition attempts occur

In power-down mode, the oscillator is stopped and the HS transistor is non-conductive while the LS transistor is conductive. The V_{DD} supply is internally clamped. The circuit is released from power-down mode by lowering the low voltage supply lower than $V_{DD(rst)}$ (mains switch reset).

An option exists to set the IC in power-down mode via external logic. The external power-down option is only available when the IC is in the boost or burn state. To enable the external power-down option, the CP pin is used. When pin CP, is connected via a 10 k Ω resistor to either PGND or SGND the voltage on pin CP is pulled down lower than $V_{th(pd)CP}$. This results in the IC entering power-down mode.

Remark: Do not connect the CP pin directly to SGND or PGND pin. Connect the SGND or PGND pin via a series 10 k Ω resistor otherwise excessive currents flow during reset and start-up state. Excessive current prevent the IC from starting up.

7.4.6 OverTemperature Protection (OTP)

The OTP circuit is designed to prevent the IC from overheating in hazardous environments. The circuit is triggered when the IC temperature exceeds the maximum temperature value $T_{j(otp)}$. OTP changes the lamp current to the level that corresponds to $V_{otp(CSI)}$ level. This condition remains until the IC temperature reduces by 20 °C (= $T_{j(otp)hys}$) and returns to the DCI controlled level.

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8. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
General						
R _{ext(RREF)}	external resistance on pin RREF	fixed nominal value 33 $\text{k}\Omega$		30	36	kΩ
SR	slew rate	on pins HBO with respect to GND		-4	+4	V/ns
T _{amb}	ambient temperature	P = 0.8 W		-40	85	°C
Tj	junction temperature			-40	+150	°C
T _{stg}	storage temperature			-55	+150	°C
Currents						
I _{i(CF)}	input current on pin CF			0	200	μΑ
Voltages						
V_{HBO}	voltage on pin HBO	operating		-	500	V
		during 1 second		-	600	V
V _{FS}	voltage on pin FS	with respect to HBO		-0.3	+14	V
V_{DD}	supply voltage			-0.3	+14	V
V _{i(CSI)}	input voltage on pin CSI			- 5	+5	V
V _{i(DCI)}	input voltage on pin DCI			0	5	V
V _{i(SLS)}	input voltage on pin SLS			-6	+6	V
V _{CI}	voltage on pin CI			0	3.5	V
V_{MDL}	voltage on pin MDL			0	5	V
ESD						
V _{ESD}	electrostatic discharge voltage	human body model:				
		all pins, except pins 14,15, and 16		-2000	+2000	V
		pins 14,15, and 16		-1000	+1000	V
		charged device model:				
		all pins		-500	+500	V
Latch-up			[1]	-	-	-

^[1] In accordance with SNW-FQ-303: all pins.

9. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air; SO16 package	100	K/W

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600 V Driver IC for dimmable compact fluorescent lamps

10. Characteristics

Table 5. Characteristics

 $V_{DD} = 13 \ V$; $V_{FS} - V_{HBO} = 13 \ V$; $T_{amb} = 25 \ ^{\circ}C$; settings according to default setting in <u>Table 6</u>, all voltages referenced to GND, positive currents flow into the IC, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Start-up state	(VDD)						
V _{DD(rst)}	reset supply voltage	high-side switch = off; low side switch = on		5.7	6.2	6.7	V
$V_{\text{DD(stop)}}$	stop supply voltage			9.6	10.0	10.4	V
V _{DD(start)}	start supply voltage			11.9	12.4	12.9	V
V _{DD(hys)}	hysteresis of supply voltage			2.2	2.4	2.6	V
V _{DD(clamp)}	clamp supply voltage	$I_{clamp(VDD)} = 5 \text{ mA}$		13.0	13.4	13.8	V
I _{DD(clamp)}	clamp supply current	V _{DD} = 14 V		20	30	-	mA
I _{DD(startup)}	start-up supply current	V _{DD} = 9 V		-	190	220	μΑ
I _{DD(pd)}	power-down supply current	$V_{DD} = 9 V$		-	190	220	μΑ
I _{DD}	supply current	default setting; $V_{DCI} = 1.4 \text{ V}$ $V_{CI} = V_{clamp(CI)}, V_{CB} = 0 \text{ V}$	[1]	-	1.6	2.0	mA
High-voltage	supply (GHS, HBO and FS	3)					
I _{leak}	leakage current	500 V on high-voltage pins		-	-	30	μΑ
Voltage contr	olled oscillator						
Output pin IC							
$V_{\text{CI(max)}}$	maximum voltage on pin CI			2.7	3.0	3.3	V
$V_{hr(CI)}$	headroom voltage on pin CI	$V_{clamp(Cl)} = V_{hr(Cl)} + V_{Cl(max)}$; burn and boost state		-	80	-	mV
Voltage contr	olled oscillator						
Output pin CF	=						
f _{bridge(max)}	maximum bridge frequency	$C_{CF} = 100 \text{ pF}; V_{CI} = 0 \text{ V}$	[2]	88	100	112	kHz
f _{bridge(bst)min}	minimum boost bridge frequency	$C_{CF} = 100 \text{ pF};$ $V_{CI} = V_{clamp(CI)}$	[2]	21	22	23	kHz
f _{bridge(min)}	minimum bridge frequency	$C_{CF} = 100 \text{ pF};$ $V_{CI} = V_{clamp(CI)}; V_{CB} = 0 \text{ V}$	[2]	38	40	42	kHz
t _{no}	non-overlap time	V _{HBO} rising edge		1.3	1.5	1.7	μ\$
		V _{HBO} falling edge		1.3	1.5	1.7	μS
V _{th(CF)max}	maximum threshold voltage on pin CF	$C_{CF} = 100 \text{ pF};$ $V_{CI} = V_{clamp(CI)}; V_{CB} = 0 \text{ V}$		2.40	2.50	2.60	V
I _{o(bst)CF}	boost output current on pin CF	$V_{CF} = 1.5 \text{ V}; V_{CI} = V_{clamp(CI)}$		-12.3	-11.8	-11.3	μΑ

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600 V Driver IC for dimmable compact fluorescent lamps

 Table 5.
 Characteristics ...continued

 $V_{DD} = 13 \text{ V}$; $V_{FS} - V_{HBO} = 13 \text{ V}$; $T_{amb} = 25 \text{ °C}$; settings according to default setting in <u>Table 6</u>, all voltages referenced to GND, positive currents flow into the IC, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{o(CF)min}$	minimum output current on pin CF	$V_{CF} = 1.5 \text{ V}; V_{CB} = 0 \text{ V};$ $V_{CI} = V_{clamp(CI)}$	-22.8	-21.8	-20.8	μΑ
I _{o(CF)max}	maximum output current on pin CF	$V_{CF} = 1.5 \text{ V}; V_{CB} = 0 \text{ V}$	-67.0	-60.0	-53.0	μΑ
Gate driver	output					
Output pins	GLS, GHS					
I _{source(drv)}	driver source current	$V_G = 4 \text{ V (GLS or GHS)};$ $V_{HBO} = 0 \text{ V; } V_{DD} = V_{FS}$ = 12 V	-105	-90	- 7 5	mA
$R_{sink(drv)}$	driver sink resistance	$V_G = 2 \text{ V (GLS or GHS)};$ $V_{HBO} = 0 \text{ V;}$ $V_{DD} = V_{FS} = 12 \text{ V}$	13	15.5	18	Ω

600 V Driver IC for dimmable compact fluorescent lamps

 Table 5.
 Characteristics ...continued

 $V_{DD} = 13 \text{ V}$; $V_{FS} - V_{HBO} = 13 \text{ V}$; $T_{amb} = 25 \text{ °C}$; settings according to default setting in <u>Table 6</u>, all voltages referenced to GND, positive currents flow into the IC, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Bootstrap dio	ode						
V _F	forward voltage	bootstrap diode; $I_{FS} = 5 \text{ mA}$; $(V_F = V_{DD} - V_{FS})$		1.3	1.7	2.1	V
Preheat curre	ent sensor						
Input: pin SL	S						
I _{I(SLS)}	input current on pin SLS	$V_{i(SLS)} = 0.4 \text{ V}$		-	-	1	μА
$V_{ph(SLS)}$	preheat voltage on pin SLS		[3]	0.57	0.60	0.63	V
Output: pin C							
I _{o(source)CI}	source output current on pin CI	$V_{CI} = 2.0 \text{ V}; V_{i(SLS)} < 0.6 \text{ V}$		-10.6	-9.6	-8.6	μΑ
I _{o(sink)CI}	sink output current on pin CI	$V_{CI} = 2.0 \text{ V}; V_{i(SLS)} > 0.6 \text{ V}$		26	29	32	μΑ
Preheat time	r, ignition timer, overcurren	t fault timer					
Pin CP							
t _{ph}	preheat time	C_{CP} = 470 nF; $R_{ext(RREF)}$ = 33 k Ω		-	0.93	-	S
t _{en(ign)}	ignition enable time	$C_{CP} = 470 \text{ nF};$ $R_{\text{ext}(RREF)} = 33 \text{ k}\Omega$		-	0.22	-	S
t _{fault(oc)}	overcurrent fault time	C_{CP} = 470 nF; $R_{ext(RREF)}$ = 33 k Ω ; initial voltage V_{CP} = 5.0 V		-	0.10	-	S
I _{o(CP)}	output current on pin CP	V _{CP} = 4.1 V; source (-) and sink (+)		5.5	5.9	6.3	μΑ
$V_{th(CP)min}$	minimum threshold voltage on pin CP			-	3.8	-	V
$V_{th(CP)max}$	maximum threshold voltage on pin CP			-	4.5	-	V
$V_{hys(CP)}$	hysteresis voltage on pin CP			0.6	0.7	0.8	V
I _{pu(CP)}	pull-up current on pin CP	V _{CP} = 3.8 V		-	-60	-	μΑ
$V_{th(pd)CP}$	power-down threshold voltage on pin CP	burn state, pin CP connected to SGND via 10 $k\Omega$		-	1.0	-	V
V _{th(rel)CP}	release threshold voltage on pin CP	hold state, $V_{DCI} = 1.4 \text{ V}$		-	2.7	-	V
Boost timer							
Pin CB							
t _{bst}	boost time	$C_{CB} = 470 \text{ nF}; T_j < 80 ^{\circ}\text{C}$		-	148	-	S
I _{o(CB)}	output current on pin CB	V _{CB} = 2.35 V; source (-) and sink (+)		0.8	1.0	1.2	μΑ
V _{th(CB)min}	minimum threshold voltage on pin CB			-	1.1	-	V

Product data sheet

600 V Driver IC for dimmable compact fluorescent lamps

 Table 5.
 Characteristics ...continued

 $V_{DD} = 13 \text{ V}$; $V_{FS} - V_{HBO} = 13 \text{ V}$; $T_{amb} = 25 \text{ °C}$; settings according to default setting in <u>Table 6</u>, all voltages referenced to GND, positive currents flow into the IC, unless otherwise specified.

1	,					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{th(CB)max}}$	maximum threshold voltage on pin CB		-	3.6	-	V
$V_{hys(CB)}$	hysteresis voltage on pin CB		2.3	2.5	2.7	V
T _{j(bp)bst}	boost bypass junction temperature	T _j sensed at end ignition time	65	80	95	°C
T _{j(end)bst}	boost end junction temperature	T _j during boost time	105	120	135	°C
I _{det(dis)bst}	boost disable detection current	$V_{CB} = 0 V$	-30	-25	-20	μА
$t_{t(bst-burn)}$	transition time from boost to burn	$C_{CP} = 470 \text{ nF}; T_j < 80 ^{\circ}\text{C}$	-	3.6	-	S
Pin CSI						
N_{LCBR}	lamp current boost ratio	V_{CSI} in boost state versus V_{CSI} in burn state; $V_{DCI} = 1.34 \text{ V}$	1.4	1.5	1.6	
Coil saturation	protection and overcurre	nt detection				
Input: pin SLS						
$V_{\text{th(sat)SLS}}$	saturation threshold voltage on pin SLS	ignition state	2.3	2.5	2.7	V
$V_{th(ocp)SLS}$	overcurrent protection threshold voltage on pin SLS	boost state and burn state	2.3	2.5	2.7	V
t _{leb}	leading edge blanking time	detection disabled first part of GLS time	-	800	-	ns
Output: pin CI						
I _{o(sink)} CI	sink output current on pin CI	V_{Cl} = 2.0 V; ignition state; $V_{i(SLS)} > V_{th(sat)SLS}$; cycle clocked	26	29	32	μА
Output: pin CF	=					
$\Delta I_{o(sat)CF}$	saturation output current difference on pin CF	V _{CF} = 1.5 V; ignition state; low-side switch = on	-	160	-	μА
Ignition curren	t detection					
Input: pin CSI						
$V_{th(det)ign(CSI)}$	ignition detection threshold voltage on pin CSI		0.55	0.60	0.65	V
t _{w(det)ign(min)}	minimum ignition detection pulse width	$V_{th(det)ign(CSI)} = 0.75 \text{ V}$ square pulse	685	885	1085	ns

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600 V Driver IC for dimmable compact fluorescent lamps

 Table 5.
 Characteristics ...continued

 $V_{DD} = 13 \text{ V}$; $V_{FS} - V_{HBO} = 13 \text{ V}$; $T_{amb} = 25 \text{ °C}$; settings according to default setting in <u>Table 6</u>, all voltages referenced to GND, positive currents flow into the IC, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Capacitive me	ode detection						
Input: pin SLS							
V _{th(capm)} SLS	capacitive mode threshold voltage on pin SLS		<u>[4]</u>	-15	- 5	0	mV
Output: pin CI							
o(sink)CI	sink output current on pin CI	V _{SLS} > V _{th(capm)SLS} ; V _{CI} = 2.0 V; ignition state or boost and burn state		26	29	32	μА
Lamp current	sensor and dimming co	ontrol					
Input: pin CSI							
R _{i(CSI)}	input resistance on pin	V _{i(CSI)} = 1 V		1	-	-	$M\Omega$
	CSI	$V_{i(CSI)} = -1 V$		40	50	60	kΩ
V _{i(CSI)}	input voltage on pin CSI	controlled feedback RMS voltage at minimum dim level; $V_{i(DCI)} = 0 \text{ V}$; $R_{\text{ext}(RREF)} = 33 \text{ k}\Omega$; $R_{\text{MDL}} = 2.0 \text{ k}\Omega$		44	50	56	mV
		controlled feedback RMS voltage at mid scale of I_{in} log curve in burn state; $V_{i(DCI)} = 0.9 \text{ V}$; $R_{\text{ext}(RREF)} = 33 \text{ kW}$		-	215	-	mV
		voltage rectification range for linear operation		-2.5	-	+2.5	V
V _{clamp(CSI)}	clamping voltage on pin CSI	100 % light output; V _{i(DCI)} ≥1.34 V		-	1.0	-	V
Input: pin DCI							
$V_{i(DCI)}$	input voltage on pin DCI	minimum voltage set by MDL pin resistor		V _{T(hec2)DCI}	-	1.34	V
R _{i(DCI)}	input resistance on pin DCI	$V_{i(CSI)} = 1 V$		1	-	-	МΩ
$V_{th(bst)DCI}$	boost threshold voltage on pin DCI			1.00	1.05	1.10	V
V _{th(bst)hys(DCI)}	hysteresis boost threshold voltage on pin DCI			80	100	120	mV
V _{th(start)DCI}	start threshold voltage on pin DCI			-	0.35	-	V
V _{th(hys)DCI}	hysteresis threshold voltage on pin DCI			80	100	120	mV
V _{T(hec1)} DCI	human eye correction 1 transition voltage on pin DCI	$V_{i(CSI)} = 0 \text{ V}; V_{MDL} = 0 \text{ V}$		-	0.17	-	V

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600 V Driver IC for dimmable compact fluorescent lamps

Table 5. Characteristics ... continued

 V_{DD} = 13 V; V_{FS} - V_{HBO} = 13 V; T_{amb} = 25 °C; settings according to default setting in <u>Table 6</u>, all voltages referenced to GND, positive currents flow into the IC, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{T(hec2)DCI}$	human eye correction 2 transition voltage on pin DCI	$\begin{split} R_{\text{ext}(\text{RREF})} &= 33 \text{ k}\Omega; \\ R_{\text{MDL}} &= 2.0 \text{ k}\Omega; \\ V_{\text{i}(\text{CSI})} &= V_{\text{clamp}(\text{CSI})} \end{split}$	-	0.44	-	V
V _{T(hec3)DCI}	human eye correction 3 transition voltage on pin DCI	$V_{i(CSI)} = 1 V$	-	1.34	-	V
V _{otp(CSI)}	overtemperature protection voltage on pin CSI	RMS voltage; $\begin{aligned} &R_{\text{ext}(\text{RREF})} = 33 \text{ k}\Omega; \\ &R_{\text{MDL}} = 2.0 \text{ k}\Omega; \\ &V_{\text{i}(\text{DCI})} = 1.5 \text{ V}; \\ &T_{\text{j}} > T_{\text{j}(\text{otp})} - T_{\text{j}(\text{otp})\text{hys}} \end{aligned}$	380	400	420	mV
Output: pin CI						
I _{o(CI)}	output current on pin CI	burn state; source (–) and sink (+); $V_{CI} = 2.0 \text{ V}$	85	95	105	μΑ
Input: pin MDI	_					
I _{source(MDL)}	source current on pin MDL		-26.3	-25.0	-23.7	μА
V_{MDL}	voltage on pin MDL	$R_{\text{ext}(\text{RREF})} = 33 \text{ k}\Omega;$ $R_{\text{MDL}} = 2.0 \text{ k}\Omega$	-	50	-	mV
Temperature p	orotection					
T _{j(otp)}	overtemperature protection junction temperature		145	160	175	°C
T _{j(otp)hys}	hysteresis overtemperature protection junction temperature		10	20	30	°C

^[1] For the default setting, see Table 6.

^[2] Switching frequency of the half-bridge output HBO. The sawtooth frequency on pin CF is twice as high.

^[3] Data sampling of V_{ph(SLS)} is performed at the end of the conduction period of the low-side power MOSFET, in preheat state.

^[4] Data sampling of V_{th(capm)SLS} is performed at the start of conduction of the low-side power MOSFET, in all states with oscillator active.

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11. Application information

11.1 Design equations

All equations are only valid for $R_{ext(RREF)} = 33 \text{ k}\Omega$

11.1.1 C_{CP} related timing equations:

• Preheat time:

$$t_{ph} = \frac{C_{CP}}{I_{o(CP)}} \times (16 \times V_{hys(CP)} + 5 - V_{th(CP)max}) \tag{1}$$

• Ignition enabling time:

$$t_{en(ign)} = \frac{C_{CP}}{I_{o(CP)}} \times 4 \times V_{hys(CP)}$$
 (2)

Overcurrent fault time:

$$t_{fault(oc)} = \frac{C_{CP}}{I_{o(CP)}} \times (5 - V_{th(CP)min})$$
(3)

• Transition to burn time:

$$t_{t(bst-burn)} = \frac{C_{CP}}{I_{o(CP)}} \times (64 \times V_{hys(CP)} + 5 - V_{th(CP)max})$$
(4)

• Restart delay time:

$$t_{d(restart)} = \frac{C_{CP}}{I_{restart(CP)}} \times (V_{th(CP)max} - V_{th(rel)CP})$$
 (5)

Where: $I_{restart(CP)} = 0.5 \mu A$ (typical)

11.1.2 C_{CB} related timing equations:

Boost time:

$$t_{bst} = \frac{C_{CB}}{I_{o(CB)}} \times (126 \times V_{hys(CB)} + V_{th(CB)min} - 0.6)$$
 (6)

11.1.3 C_{CF} related frequency equations:

Maximum bridge frequency:

$$f_{bridge(max)} = \frac{0.5}{\frac{C_{CF} + C_{par}}{I_{o(CF)max}} \times V_{th(CF)max} + t_{dch}}$$
(7)

• Minimum bridge frequency with disabled boost:

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$$f_{bridge(min)} = \frac{0.5}{\frac{C_{CF} + C_{par}}{I_{o(CF)min}} \times V_{th(CF)max} + t_{dch}}$$
(8)

• Minimum bridge frequency with enabled boost:

$$f_{bridge(bst)min} = \frac{0.5}{\frac{C_{CF} + C_{par}}{I_{o(bst)CF}} \times V_{th(CF)max} + t_{dch}}$$
(9)

Where: C_{par} = 4.7 [pF] and t_{dch} = 0.4 [µs] (typical)

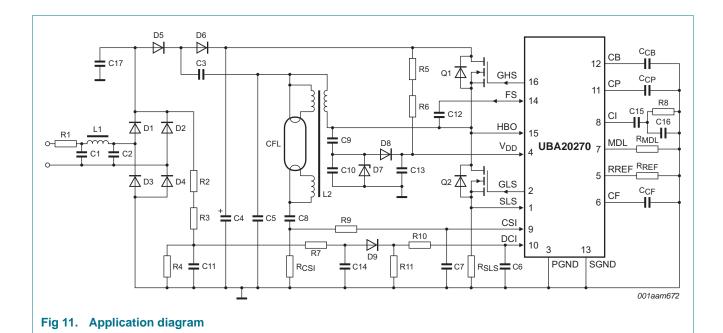
11.1.4 R_{SLS} related preheat current:

$$I_{ph(M)} = \frac{V_{ph(SLS)}}{R_{SLS}} \qquad I_{ph(RMS)} \approx \frac{V_{ph(SLS)}}{R_{SLS} \times \sqrt{3}}$$
 (10)

11.1.5 R_{MDL} related MDL:

• MDL threshold voltage:

$$V_{MDL} = R_{MDL} \times I_{source(MDL)} \tag{11}$$



Detailed in Table 6 is a list of typical application components. See Figure 11.

Table 6. Typical components for a 230 V mains application

21	The second secon	1.0
Reference	Component UBA20270	Description
R1	10 Ω	2 W fusible resistor
R2, R3	220 kΩ	
R4	22 kΩ	

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 Table 6.
 Typical components for a 230 V mains application ...continued

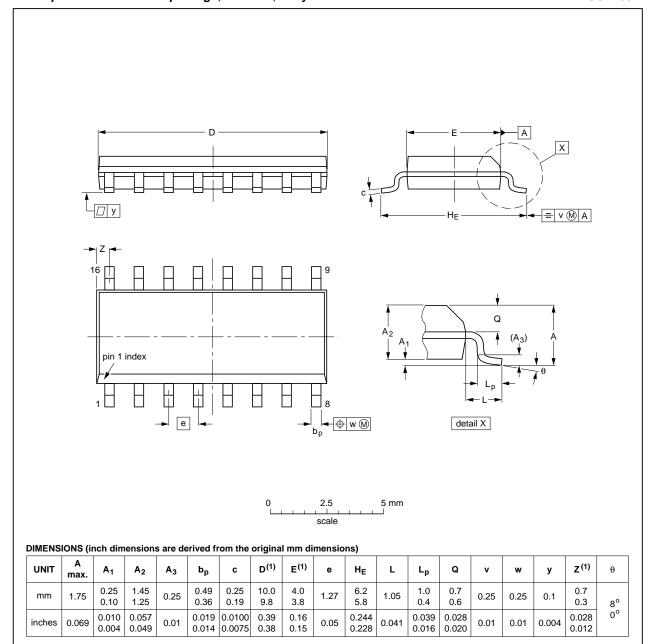
Reference	Component UBA20270	Description
R5, R6	330 kΩ	
R7, R10	100 kΩ	
R8	1 kΩ	
R9	1 kΩ	
R11	39 kΩ	
R _{REF}	33 kΩ; 1 %	
R _{SLS}	1.2 Ω	
R _{MDL}	1 kΩ	
R _{CSI}	8.2 Ω	adjust for nominal lamp current
C1, C2	22 nF; 630 V	
C3	3.3 nF; 1000 V	
C4	10 μF; 400 V	
C5	4.7 nF; 1000 V	lamp capacitor
C6, C14	470 nF	
C7	100 pF	
C8	47 nF; 400 V	
C9	560 pF; 500 V	V _{DD} charge pump capacitor
C10	not mounted	
C11	4.7 nF	
C12	100 nF	
C13	470 nF	
C15	220 nF	
C16	not mounted	
C17	22 nF; 400 V	
C _{CB}	150 nF	
C_{CP}	470 nF	
C_{CF}	100 pF; 2 %	
Q1, Q2	SPS02N60C3	
D1 to D4	1N4007	
D5, D6	1N4937	
D7	BZX84JC12	
D8	1N4148	
L1	4.7 mH	mains filter inductor; $I_{SAT} = 300 \text{ mA}$
L2	2000/2/2 μΗ	lamp inductor
D9	1N4148	

600 V Driver IC for dimmable compact fluorescent lamps

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN	ISSUE DATE	
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig 12. Package outline SOT109-1 (SO16)

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600 V Driver IC for dimmable compact fluorescent lamps

13. Abbreviations

Table 7. Abbreviations

Acronym	Description
CFL	Compact Fluorescent Lamp
CMP	Capacitive Mode Protection
DSR	Double-Sided Rectifier
ESD	ElectroStatic Discharge
HS	High-Side
LS	Low-Side
MDL	Minimum Dimming Level
OCP	OverCurrent Protection
OPP	OverPower Protection
ОТА	Operational Transconductance Amplifier
OTP	OverTemperature Protection
RMS	Root Mean Square
SR	Slew Rate
UVLO	UnderVoltage LockOut
VCO	Voltage Controlled Oscillator

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14. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
UBA20270 v.2	20110908	Prroduct data sheet	-	UBA20270 v.1
UBA20270 v.1	20110816	Preliminary data sheet	-	-

600 V Driver IC for dimmable compact fluorescent lamps

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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600 V Driver IC for dimmable compact fluorescent lamps

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